

H11L1, H11L2, H11L3, H11L4



ISOCOM
COMPONENTS

**MICROPROCESSOR COMPATIBLE
SCHMITT TRIGGER OPTICALLY
COUPLED ISOLATOR**



DESCRIPTION

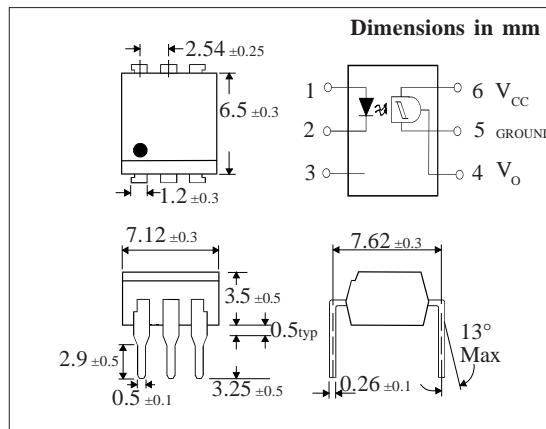
The H11L1, 2, 3, 4 series are optically coupled isolators consisting of a Gallium Arsenide infrared emitting diode and a Microprocessor Compatible Schmitt trigger output mounted in a standard 6 pin dual in line package.

FEATURES

- Options :-
10mm lead spread - add G after part no.
Surface mount - add SM after part no.
Tape&reel - add SMT&R after part no.
- High data rate, 1MHz typical (NRZ)
- Microprocessor compatible drive
- Logic compatible output sinks 16 milliamperes at 0.4 volts maximum
- High Isolation Voltage(5.3kV_{RMS},7.5kV_{PK})
- High common mode rejection ratio
- Fast switching : t_{rise}, t_{fall} = 100nS typical
- Wide supply voltage capability, compatible with all popular logic systems
- Guaranteed On / Off threshold hysteresis

APPLICATIONS

- Logic to logic isolator
- Line receiver-eliminates noise and transient problems
- Programmable current level sensor
- AC to TTL conversion - square wave shaping
- Digital programming of power supplies
- Interfaces computers with peripherals



**ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)**

Storage Temperature	-40°C to +125°C
Operating Temperature	-25°C to +85°C
Lead Soldering Temperature (1/16 inch (1.6mm) from case for 10 secs)	260°C

INPUT DIODE

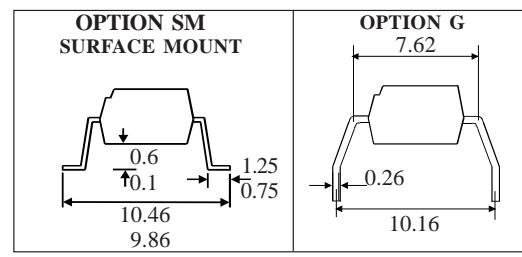
Forward Current, I _F	50mA
Peak forward current (Pulse width ≤ 100μS, Duty ratio=0.001)	1A
Reverse Voltage, V _R	6V
Power Dissipation (derate linearly 1.41mW / °C above 25°C)	70mW

OUTPUT DETECTOR

Output Voltage, V _{CC}	16V
Supply Voltage, V _{OH}	16V
Output current, I _{OL}	50mA
Power Dissipation (derate linearly 2mW / °C above 25°C)	150mW

POWER DISSIPATION

Total Power Dissipation (derate linearly 2.94mW / °C above 25°C)	170mW
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ISOCOM COMPONENTS 2004 LTD

Unit 25B, Park View Road West,
Park View Industrial Estate, Brenda Road
Hartlepool, Cleveland, TS25 1UD
Tel: (01429) 863609 Fax: (01429) 863581

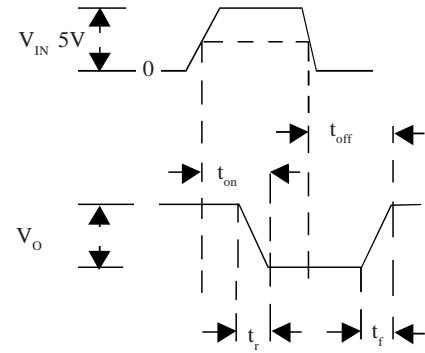
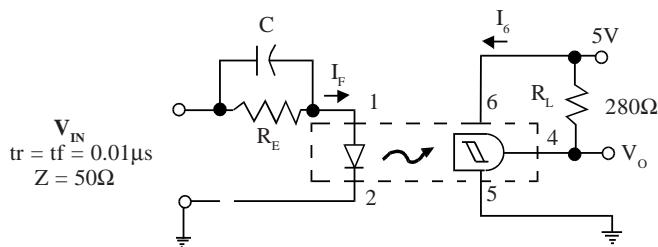
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)	0.75 10 100		V μA pF	V mA μA	$I_F = 0.3\text{mA}$
	Forward Voltage (V_F)					$I_F = 10\text{mA}$
	Reverse Current (I_R)					$V_R = 3\text{V}$
	Capacitance (C_J)					$V = 0, f = 1\text{MHz}$
Output	Operating Voltage Range (V_{CC})	3	1.6	15 5 100	V mA μA	$I_F = 0\text{mA}, V_{CC} = 5\text{V}$
	Supply Current I_6 (off)					$I_F = 0\text{mA}, V_{CC} = V_o = 15\text{V}$
	Output Current High (I_{OH})					
Coupled	Supply Current I_6 (on)	1.6	5 0.4	mA V	$I_F = 10\text{mA}, V_{CC} = 5\text{V}$ $R_L = 270\Omega, V_{CC} = 5\text{V}$	
	Output Voltage, Low (V_{OL})					$R_L = 270\Omega, V_{CC} = 5\text{V}$
	Turn-on Threshold Current I_F (on)					$R_L = 270\Omega, V_{CC} = 5\text{V}$
	H1IL1					$R_L = 270\Omega, V_{CC} = 5\text{V}$
	H1IL2					$R_L = 270\Omega, V_{CC} = 5\text{V}$
	H1IL3					$R_L = 270\Omega, V_{CC} = 5\text{V}$
	H1IL4					$R_L = 270\Omega, V_{CC} = 5\text{V}$
	Turn-off Threshold Current I_F (off)					$R_L = 270\Omega, V_{CC} = 5\text{V}$
	Hysteresis Ratio I_F (off) / I_F (on)					$R_L = 270\Omega, V_{CC} = 5\text{V}$
	Input to Output Isolation Voltage V_{ISO}			V_{RMS} V_{PK}	μs	See note 1
	5300					See note 1
	7500					
	High to Low Propagation time	t_{PHL}	1	V_{PK}	μs	$R_E = 280\Omega$
	Fall Time					$V_{CC} = 5\text{V}$
	Low to High Propagation time	t_{PLH}	2	V_{PK}	μs	$I_F = 4\text{mA}$
	Rise Time					

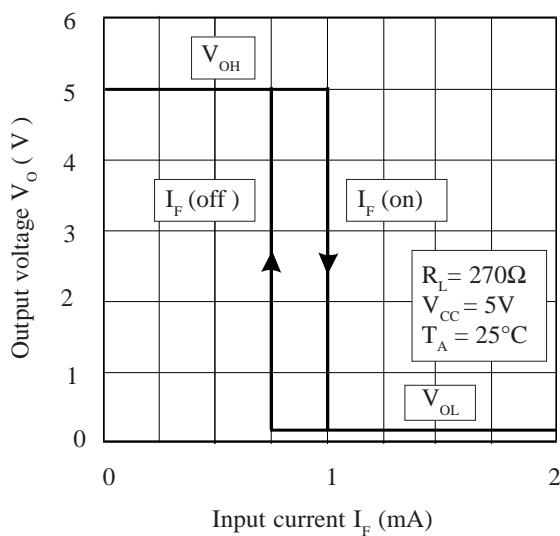
Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

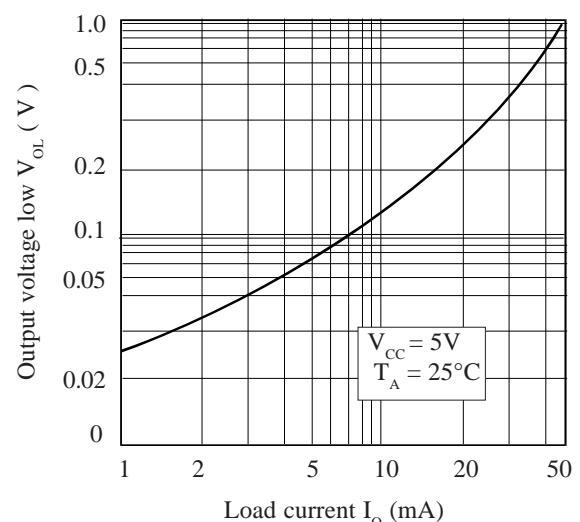
SWITCHING CHARACTERISTICS



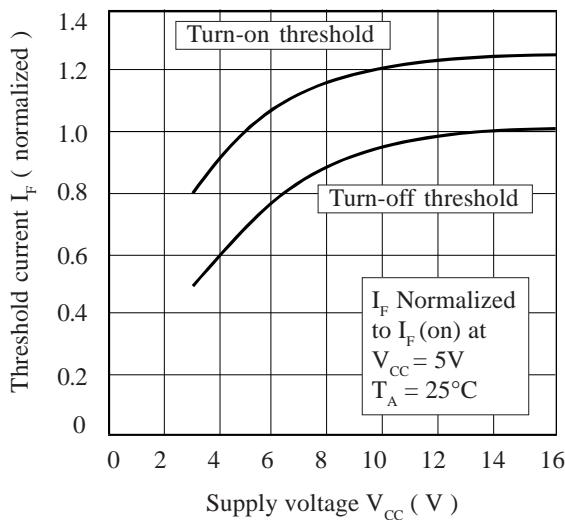
Transfer Characteristics



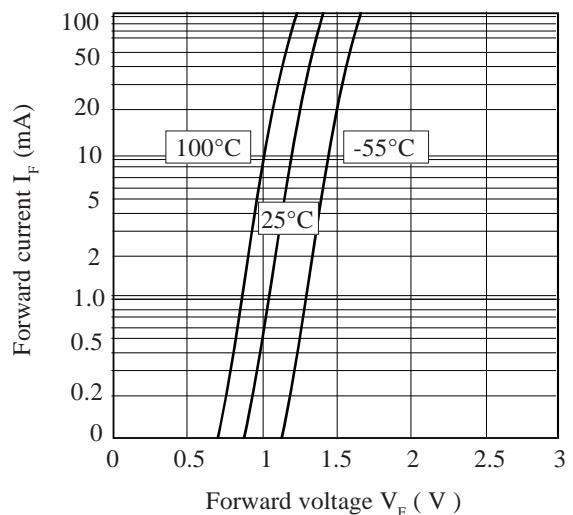
On Voltage vs. Load Current



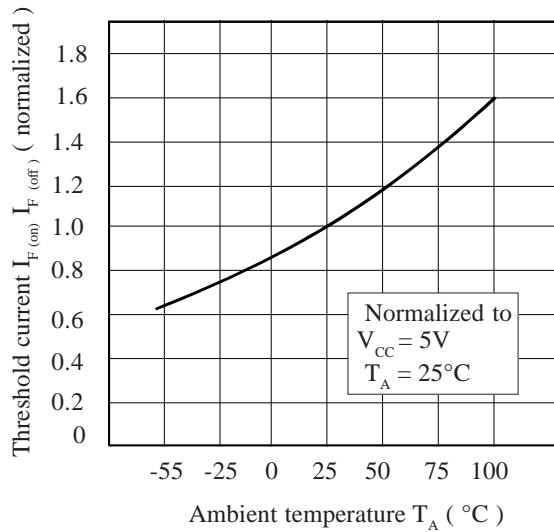
Threshold Current vs. Supply Voltage



Forward Voltage vs. Forward Current



Threshold Current vs. Ambient Temperature



Supply Current vs. Supply Voltage

